NSN 5961-01-196-9455

Unitized Semiconductor Devices - Page 1 of 1



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Component Name And Quantity:
2 transistor
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
80.0 collector to emitter voltage, dc with specified circuit between base and emitter all transistor
Current Rating Per Characteristic:
25.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
400.0 watts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
85.0 degrees celsius ambient air
Special Features:
All transistor junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0